

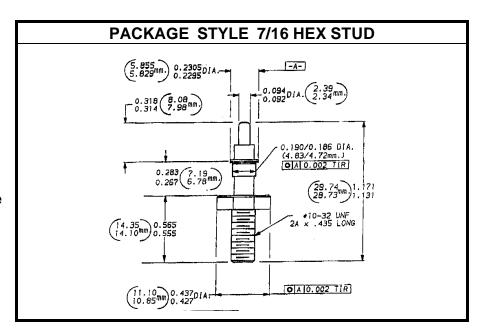
SILICON STEP RECOVERY DIODE



The **DVB4376-99** is Designed for use in Moderate Power Multiplier Applications, Cathode Connected to Case.

MAXIMUM RATINGS





CHARACTERISTICS T_C = 25 °C

SYMBOL	TEST CONDITIONS		MINIMUM	TYPICAL	MAXIMUM	UNITS
V_{B}	I _R = 10 μA		85			V
C _t	V _R = 0 V	f = 1.0 MHz		12		pF
Ct	V _R = 6.0 V	f = 1.0 MHz	8.0		11.5	pF
T _L	MINORITY CARRIER LIFETIME				400	m6